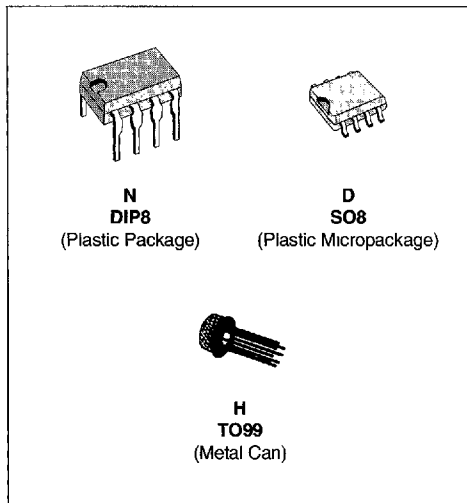


GENERAL PURPOSE DUAL JFET OPERATIONAL AMPLIFIERS

- LOW POWER CONSUMPTION
- WIDE COMMON-MODE (UP TO V_{CC}^+) AND DIFFERENTIAL VOLTAGE RANGE
- LOW INPUT BIAS AND OFFSET CURRENT
- OUTPUT SHORT-CIRCUIT PROTECTION
- HIGH INPUT IMPEDANCE J-FET INPUT STAGE
- INTERNAL FREQUENCY COMPENSATION
- LATCH UP FREE OPERATION
- HIGH SLEW RATE : $16V/\mu s$ (typ)



DESCRIPTION

These circuits are high speed J-FET input dual operational amplifiers incorporating well matched, high voltage J-FET and bipolar transistors in a monolithic integrated circuit.

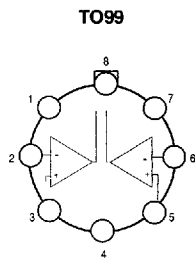
The devices feature high slew rates, low input bias and offset current, and low offset voltage temperature coefficient.

ORDER CODES

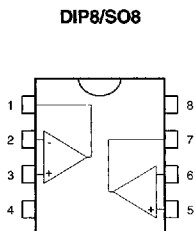
Part Number	Temperature	Package		
		H	N	D
MC34002/A/B	0°C, +70°C	•	•	•
MC33002/A/B	-40°C, +105°C	•	•	•
MC35002/A/B	-55°C, +125°C	•	•	•

33002-01 TBL

PIN CONNECTIONS (top views)



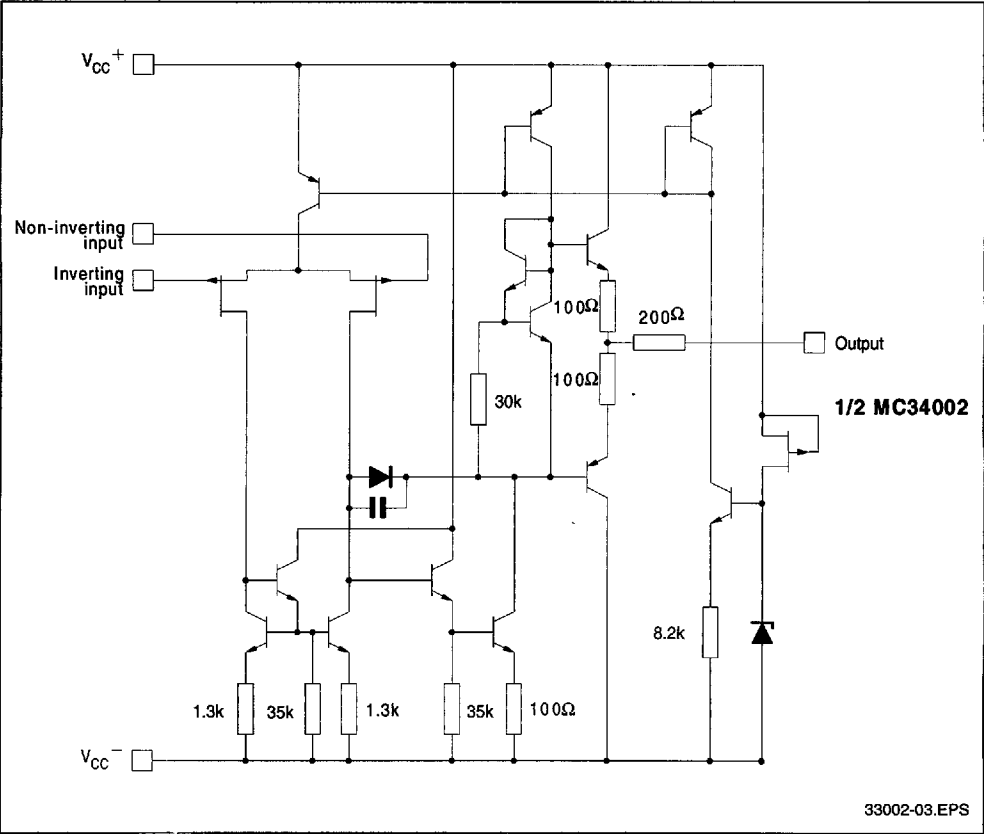
33002-01 EPS



33002-02.EPS

- 1 - Output 1
- 2 - Inverting input 1
- 3 - Non-inverting input 1
- 4 - V_{CC}^+
- 5 - Non-inverting input 2
- 6 - Inverting input 2
- 7 - Output 2
- 8 - V_{CC}^+

SCHEMATIC DIAGRAM



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter		Value	Unit
V _{CC}	Supply Voltage - (note 1)		±18	V
V _I	Input Voltage - (note 3)		±15	V
V _{id}	Differential Input Voltage - (note 2)		±30	V
P _{tot}	Power Dissipation		680	mW
	Output Short-circuit Duration (note 4)		Infinite	
T _{oper}	Operating Free Air Temperature Range	MC34002, A, B MC33002, A, B MC35002, A, B	0 to 70 -40 to 105 -55 to 125	°C
T _{stg}	Storage Temperature Range		-65 to 150	°C

- Notes :
- 1 All voltage values, except differential voltage, are with respect to the zero reference level (ground) of the supply voltages where the zero reference level is the midpoint between V_{CC}⁺ and V_{CC}⁻.
 - 2 Differential voltages are at the non-inverting input terminal with respect to the inverting input terminal.
 - 3 The magnitude of the input voltage must never exceed the magnitude of the supply voltage or 15 volts, whichever is less.
 - 4 The output may be shorted to ground or to either supply. Temperature and /or supply voltages must be limited to ensure that the dissipation rating is not exceeded.

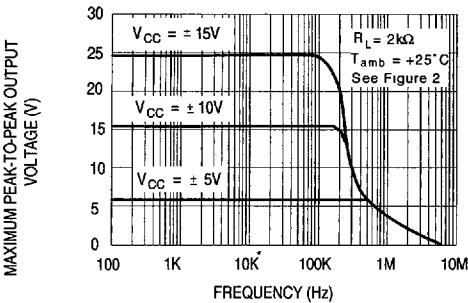
ELECTRICAL CHARACTERISTICS

V_{CC} = ±15V, T_{amb} = 25°C (unless otherwise specified)

Symbol	Parameter	MC35002A,B MC33002A,B MC34002A,B			MC35002 MC33002 MC34002			Unit
		Min.	Typ.	Max.	Min.	Typ.	Max.	
V _{io}	Input Offset Voltage (R _S ≤ 10kΩ) T _{amb} = 25°C MC35002B, MC34002B, MC33002B MC35002A, MC34002A, MC33002A T _{min} ≤ T _{amb} ≤ T _{max} MC35002B, MC34002B, MC33002B MC35002A, MC34002A, MC33002A		3 1	5 2		3 13	10	mV
DV _{io}	Input Offset Voltage Drift		10			10		μV/°C
I _{io}	Input Offset Current * T _{amb} = 25°C T _{min} ≤ T _{amb} ≤ T _{max}		5	50 4		5 100 4		pA nA
I _{ib}	Input Bias Current * T _{amb} = 25°C T _{min} ≤ T _{amb} ≤ T _{max}		20	200 20		20 200 20		pA nA
A _{vd}	Large Signal Voltage Gain (R _L = 2kΩ, V _O = ±10V) T _{amb} = 25°C T _{min} ≤ T _{amb} ≤ T _{max}	50 25	200		25 15	200		V/mV
SVR	Supply Voltage Rejection Ratio (R _S ≤ 10kΩ) T _{amb} = 25°C T _{min} ≤ T _{amb} ≤ T _{max}	80 80	86		70 70	86		dB
I _{CC}	Supply Current, per Amp, no Load T _{amb} = 25°C T _{min} ≤ T _{amb} ≤ T _{max}		1.4	2.5 2.8		1.4 2.5 2.8		mA
V _{icm}	Input Common Mode Voltage Range	±11	+15 -12		±11	+15 -12		V
CMR	Common Mode Rejection Ratio (R _S ≤ 10kΩ) T _{amb} = 25°C T _{min} ≤ T _{amb} ≤ T _{max}	80 80	86		70 70	86		dB
I _{os}	Output Short-circuit Current T _{amb} = 25°C T _{min} ≤ T _{amb} ≤ T _{max}	10 10	40	60 60	10 10	40 60 60		mA
±V _{OPP}	Output Voltage Swing T _{amb} = 25°C T _{min} ≤ T _{amb} ≤ T _{max} R _L = 2kΩ R _L = 10kΩ R _L = 2kΩ R _L = 10kΩ	10 12 10 12	12 13.5		10 12 10 12	12 13.5		V
SR	Slew Rate (V _{in} = 10V, R _L = 2kΩ, C _L = 100pF, T _{amb} = 25°C, unity gain)	12	16		12	16		V/μs
t _r	Rise Time (V _{in} = 20mV, R _L = 2kΩ, C _L = 100pF, T _{amb} = 25°C, unity gain)		0.1			0.1		μs
K _{OV}	Overshoot (V _{in} = 20mV, R _L = 2kΩ, C _L = 100pF, T _{amb} = 25°C, unity gain)		10			10		%
GBP	Gain Bandwidth Product (f = 100kHz, T _{amb} = 25°C, V _{in} = 10mV, R _L = 2kΩ, C _L = 100pF)	2.5	4		2.5	4		MHz
R _i	Input Resistance		10 ¹²			10 ¹²		Ω
THD	Total Harmonic Distortion (f = 1kHz, A _V = 20dB, R _L = 2kΩ, C _L = 100pF, T _{amb} = 25°C, V _O = 2V _{PP})		0.01			0.01		%
e _n	Equivalent Input Noise Voltage (f = 1kHz, R _S = 100Ω)		15			15		$\frac{nV}{\sqrt{Hz}}$
∅ _m	Phase Margin		45			45		Degrees
V _{O1} /V _{O2}	Channel Separation (A _{vd} = 100)		120			120		dB

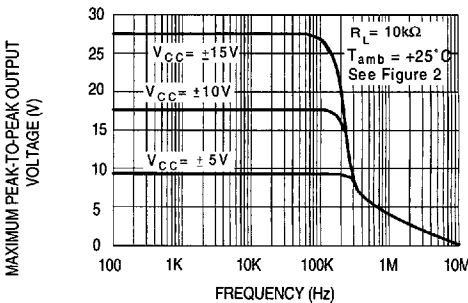
* The input bias currents are junction leakage currents which approximately double for every 10°C increase in the junction temperature

MAXIMUM PEAK-TO-PEAK OUTPUT
VOLTAGE VERSUS FREQUENCY



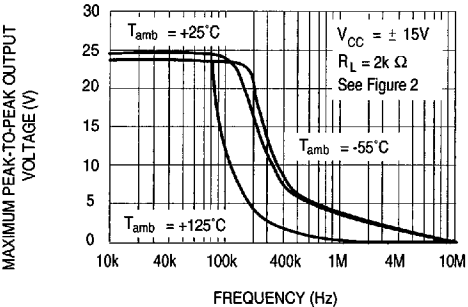
33002-04.EPS

MAXIMUM PEAK-TO-PEAK OUTPUT
VOLTAGE VERSUS FREQUENCY



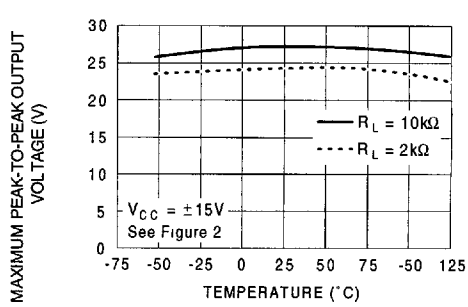
33002-05.EPS

MAXIMUM PEAK-TO-PEAK OUTPUT
VOLTAGE VERSUS FREQUENCY



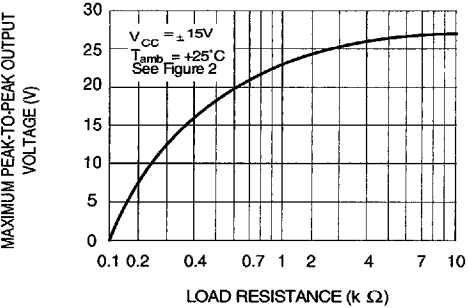
33002-06.EPS

MAXIMUM PEAK-TO-PEAK OUTPUT
VOLTAGE VERSUS FREE AIR TEMP.



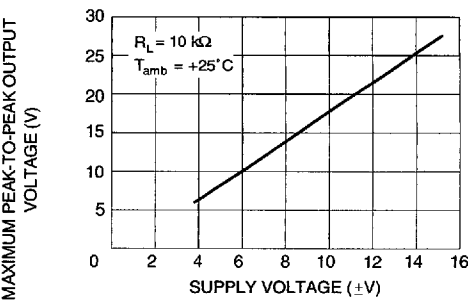
33002-07.EPS

MAXIMUM PEAK-TO-PEAK OUTPUT
VOLTAGE VERSUS LOAD RESISTANCE



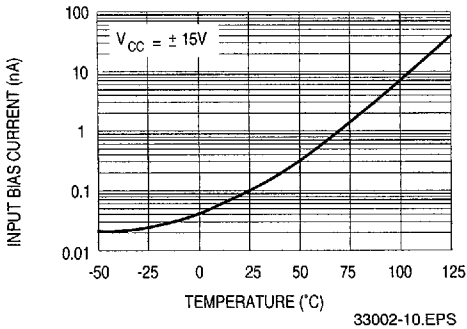
33002-08.EPS

MAXIMUM PEAK-TO-PEAK OUTPUT
VOLTAGE VERSUS SUPPLY VOLTAGE

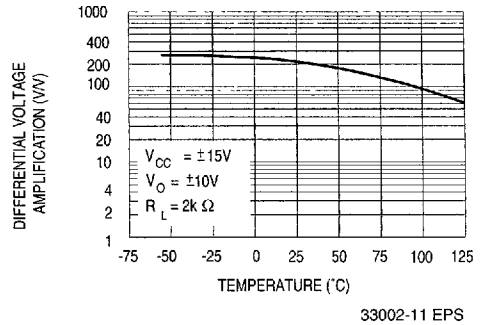


33002-09.EPS

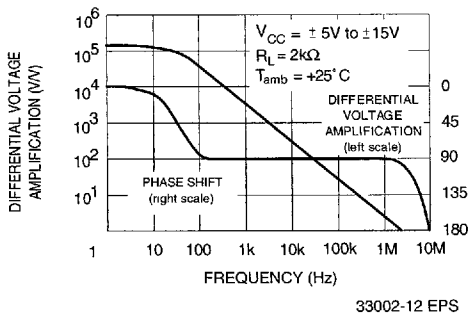
INPUT BIAS CURRENT VERSUS FREE AIR TEMPERATURE



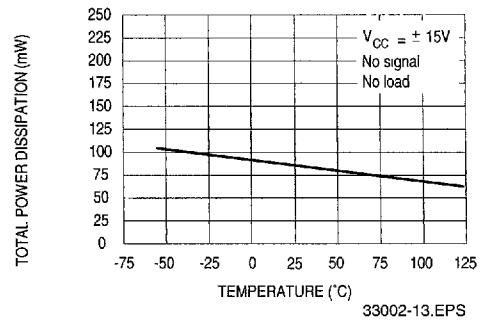
LARGE SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION VERSUS FREE AIR TEMPERATURE



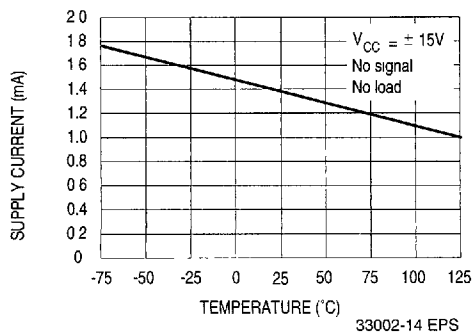
LARGE SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION AND PHASE SHIFT VERSUS FREQUENCY



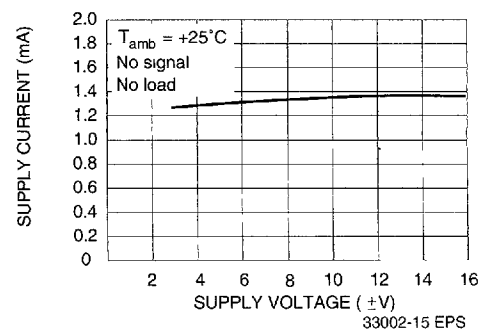
TOTAL POWER DISSIPATION VERSUS FREE AIR TEMPERATURE



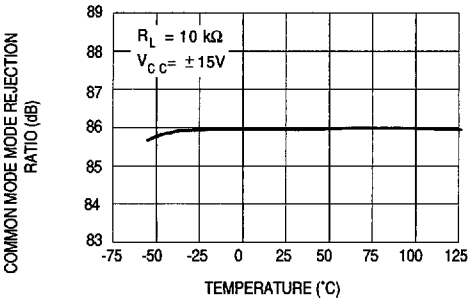
SUPPLY CURRENT PER AMPLIFIER VERSUS FREE AIR TEMPERATURE



SUPPLY CURRENT PER AMPLIFIER VERSUS SUPPLY VOLTAGE

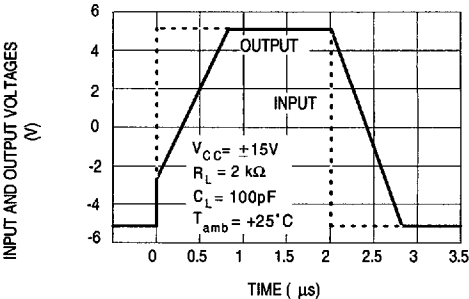


COMMON MODE REJECTION RATIO
VERSUS FREE AIR TEMPERATURE



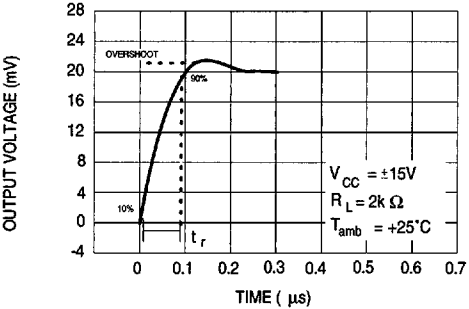
33002-16.EPS

VOLTAGE FOLLOWER LARGE SIGNAL
PULSE RESPONSE



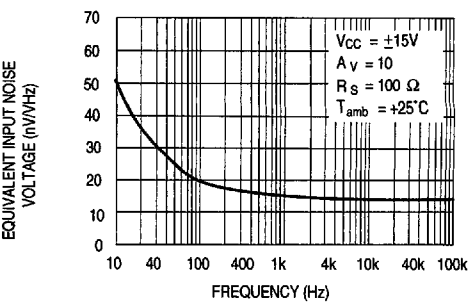
33002-17.EPS

OUTPUT VOLTAGE VERSUS
ELAPSED TIME



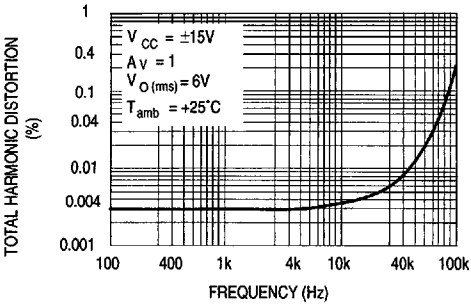
33002-18.EPS

EQUIVALENT INPUT NOISE VOLTAGE
VERSUS FREQUENCY



33002-19.EPS

TOTAL HARMONIC DISTORTION VERSUS
FREQUENCY



33002-20.EPS

PARAMETER MEASUREMENT INFORMATION

Figure 1 : Voltage Follower

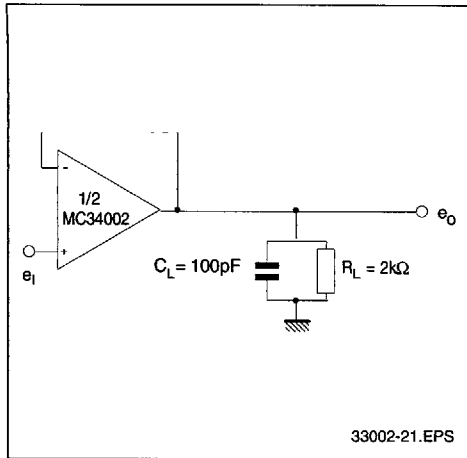
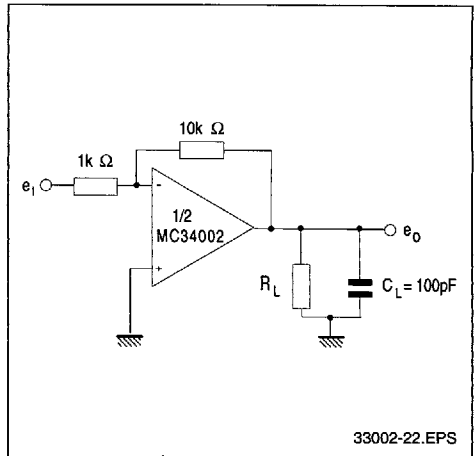


Figure 2 : Gain-of-10 Inverting Amplifier



TYPICAL APPLICATION

100KHz QUADRUPLE OSCILLATOR

